



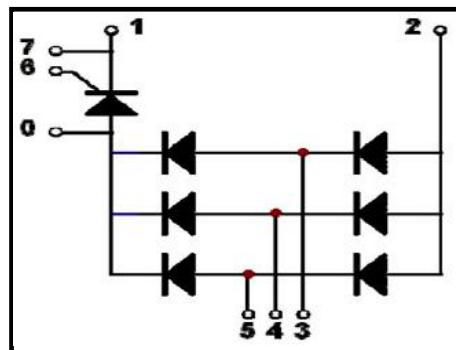
## Features

- Isolated Module Package
- Isolation voltage 3000 V
- Three Phase Bridge and a Thyristor



## Applications

- Current Stabilized Power Supply
- Switching Power Supply
- Inverter For AC or DC Motor Control



## ■ Diode

### ABSOLUTE MAXIMUM RATINGS

$T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Max.	Unit
$V_{RRM}$	Repetitive Reverse Voltage		1600	V
$I_{D(AV)}$	Average Forward Current	$T_C=90^\circ\text{C}$ , moudle	100	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	1200	A
		$T_J=45^\circ\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	1300	A
$I^2t$	$I^2t$ (For Fusing)	$T_J=45^\circ\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	7.2	$\text{KA}^2\text{s}$
		$T_J=45^\circ\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	8.4	$\text{KA}^2\text{s}$
$T_J$	Junction Temperature		-40 to +150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range		-40 to +125	$^\circ\text{C}$
$V_{isol}$	Insulation Test Voltage	AC, 50Hz, $t=1\text{min}$	3000	V
Weight			215	g

### ELECTRICAL AND THERMAL CHARACTERISTICS

$T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{RM}$	Reverse Leakage Current	$V_R=1600\text{V}$	--	--	500	$\mu\text{A}$
		$V_R=1600\text{V}$ , $T_J=125^\circ\text{C}$	--	--	5	mA
$V_F$	Forward Voltage	$I_F=100\text{A}$	--	1.15	--	V
		$I_F=100\text{A}$ , $T_J=125^\circ\text{C}$	--	1.1	--	V
$R_{θJC}$	Thermal Resistance Junction-to-Case	per diode	--	--	0.9	$^\circ\text{C}/\text{W}$
		per module	--	--	0.15	$^\circ\text{C}/\text{W}$
$R_{θCS}$	Thermal Resistance Case -to-Sink	per diode	--	--	0.42	$^\circ\text{C}/\text{W}$
		per module	--	--	0.07	$^\circ\text{C}/\text{W}$

■ Thyristor

**ABSOLUTE MAXIMUM RATINGS**

T<sub>C</sub>=25°C unless otherwise specified

Symbol	Test Condition	Value	Unit
V <sub>RRM</sub>		1600	V
I <sub>T(AV)</sub>	T <sub>C</sub> =90°, 180° conduction, half sine wave;	100	A
I <sub>TSM</sub>	T <sub>J</sub> =45°, t=10ms (50Hz), sine, V <sub>R</sub> =V <sub>RRM</sub> ;	1500	A
	T <sub>J</sub> =45°, t=8.3 ms (60Hz), sine, V <sub>R</sub> =V <sub>RRM</sub> ;	1650	
I <sup>2</sup> t	T <sub>J</sub> =45°, t=10ms (50Hz), sine, V <sub>R</sub> =V <sub>RRM</sub> ;	9.1	KA <sup>2</sup> s
	T <sub>J</sub> =45°, t=8.3 ms (60Hz), sine, V <sub>R</sub> =V <sub>RRM</sub> ;	9.8	
dV/dt	T <sub>J</sub> =125°, exponential to 67% rated V <sub>DRM</sub>	1000	V/us
dl/dt	T <sub>J</sub> =125°, I <sub>TM</sub> =314A, rated V <sub>DRM</sub>	150	A/us
V <sub>ISOL</sub>	50Hz, all terminals shorted, t=1s, I <sub>ISOL</sub> ≤1mA ;	3000	V~
T <sub>J</sub>	Max. junction operating temperature range	-40~125	°K
T <sub>STG</sub>	Max. storage temperature range	-40~125	°C
	Mounting torque(M6)	3 to 5	N·m
	Terminal connection torque(M6)	3 to 5	N·m
	Terminal connection torque(M4)	1 to 2	N·m

**ELECTRICAL AND THERMAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

Symbol	Test Condition	Min.	Typ.	Max.	Unit
I <sub>DRM</sub> /I <sub>RRM</sub>	T <sub>J</sub> =125°, V <sub>D</sub> =V <sub>R</sub> =1600V;			50	mA
V <sub>TM</sub>	I <sub>TM</sub> =314A, t <sub>d</sub> =10 ms, half sine;		1.54		V
V <sub>GT</sub>	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω, T <sub>j</sub> =-40°C;			4	V
	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω;			2.5	
	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω, T <sub>j</sub> =125°C;			1.7	
I <sub>GT</sub>	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω, T <sub>j</sub> =-40°C;			270	mA
	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω;			150	
	V <sub>A</sub> =6V, R <sub>A</sub> =1Ω, T <sub>j</sub> =125°C;			80	
P <sub>GM</sub>	tp≤5ms, T <sub>j</sub> =125°C;			12	W
P <sub>GM(AV)</sub>	f=50Hz, T <sub>j</sub> =125°C;			3	W
R <sub>thjc</sub>	Thermal Resistance, Junction-to-Case			0.3	K/W
R <sub>thcs</sub>	Thermal Resistance, Case -to-Sink			0.07	K/W

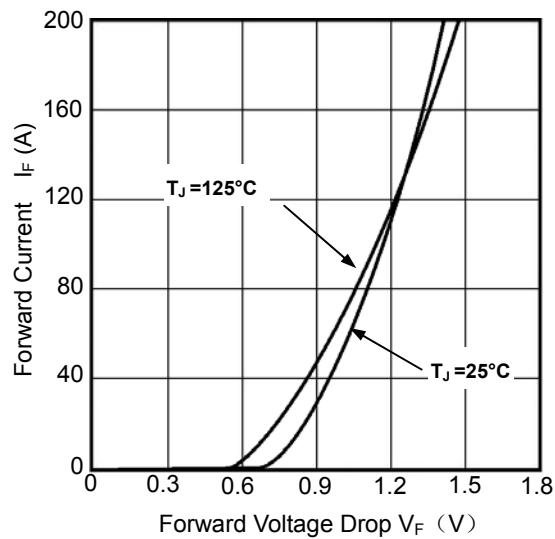
**Characteristic curves**


Figure 1. Diode Forward Voltage Drop vs Forward Current

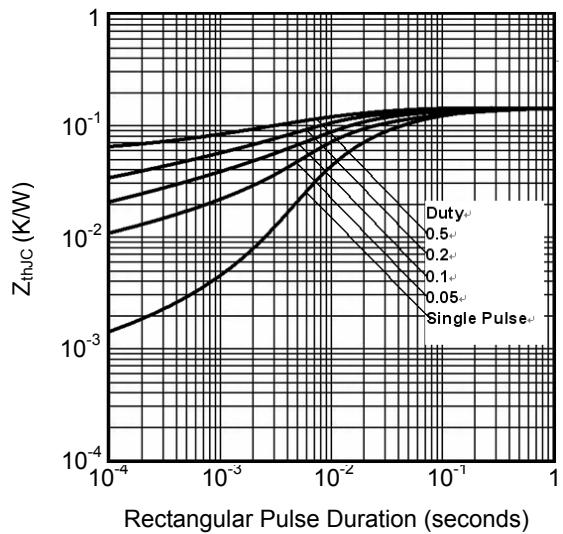


Figure 2. Diode Thermal Impedance  $Z_{\text{thJC}}$

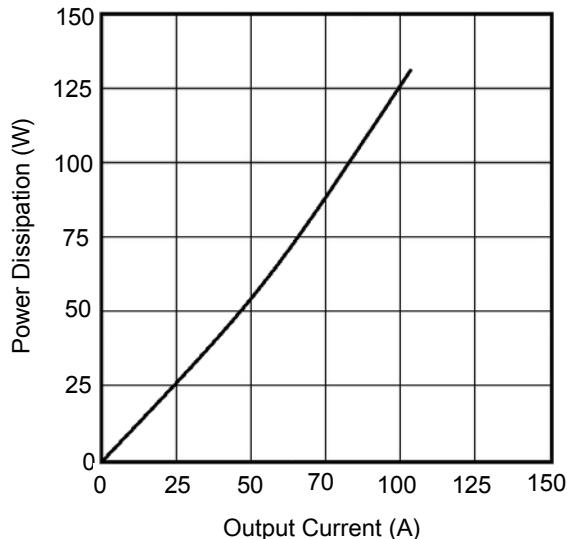


Figure 3. SCR Output Current vs Power Dissipation

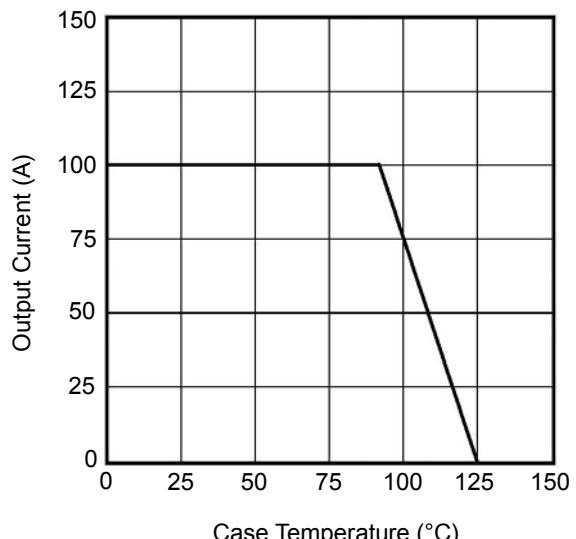


Figure 4. SCR Output Current vs Case Temperature

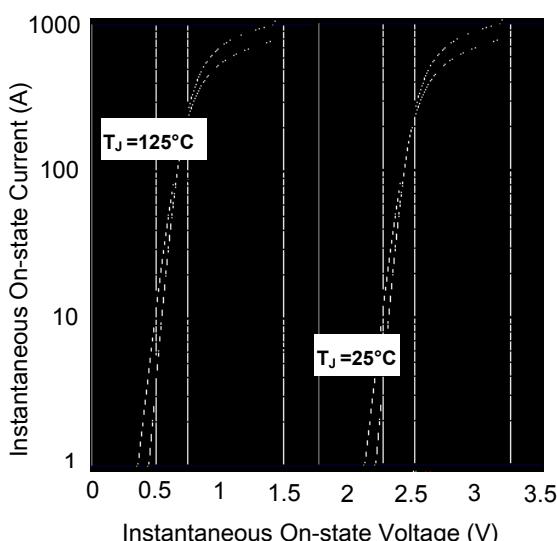


Figure 5. SCR On State Voltage Drop

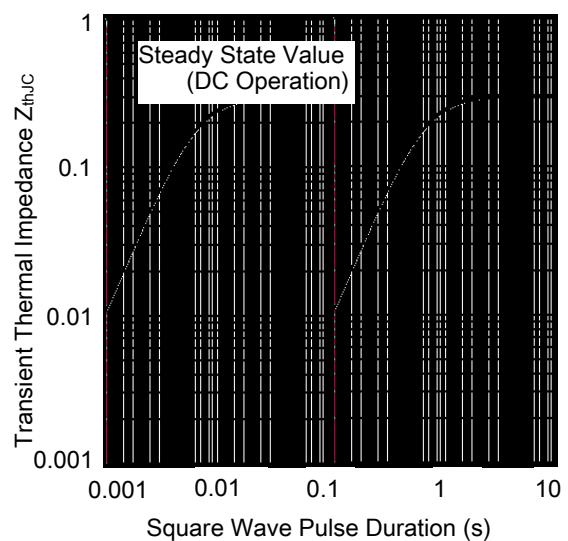


Figure 6. SCR Thermal Impedance  $Z_{\text{thJC}}$

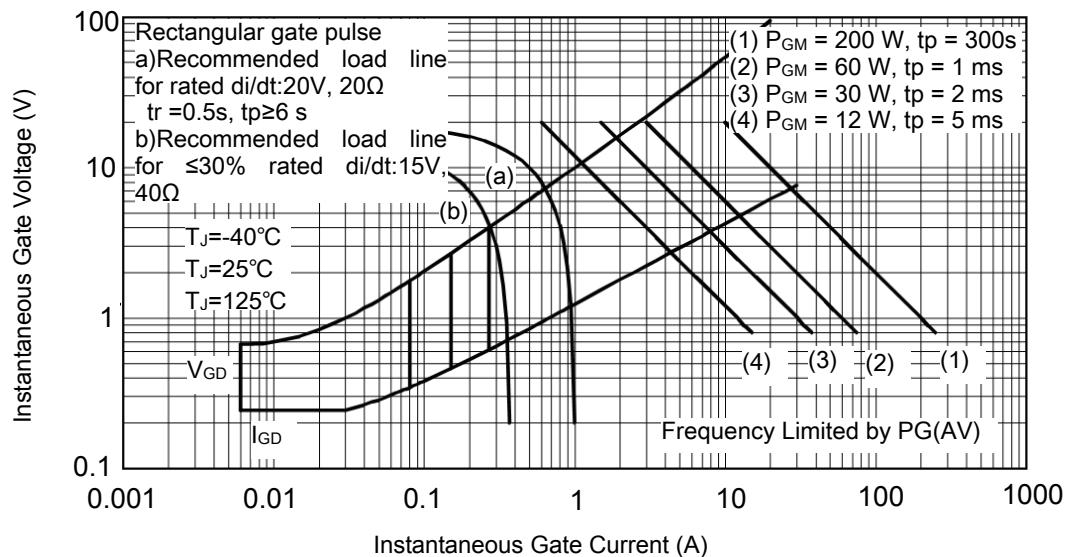


Figure 7. Gate Characteristics

### Package Outline (Dimensions in mm)

